NSN 5961-01-336-7778

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View Online at https://aerobasegroup.com/nsn/5961-01-336-7778 **Inclosure Material:** Plastic **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.080 inches and 0.105 inches **Overall Width:** Between 0.175 inches and 0.205 inches **Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-226aa **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 drain to gate voltage and 60.0 drain to source voltage and 40.0 gate to source voltage **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current of standard range **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: